Low-power dual PCB configurable multiple function gate Rev. 3 — 22 July 2019 Product data sheet

### 1. General description

The 74AUP2G97 is a dual configurable multiple function gate with Schmitt-trigger inputs. Each gate within the device can be configured as any of the following logic functions MUX, AND, OR, NAND, NOR, inverter and buffer; using the 3-bit input. All inputs can be connected directly to  $V_{CC}$  or GND.

This device ensures very low static and dynamic power consumption across the entire  $V_{CC}$  range from 0.8 V to 3.6 V.

This device is fully specified for partial power down applications using  $I_{OFF}$ . The  $I_{OFF}$  circuitry disables the output, preventing the potentially damaging backflow current through the device when it is powered down.

## 2. Features and benefits

- Wide supply voltage range from 0.8 V to 3.6 V
- High noise immunity
- ESD protection:
  - HBM JESD22-A114F exceeds 5000 V
  - MM JESD22-A115-A exceeds 200 V
  - CDM JESD22-C101E exceeds 1000 V
- Low static power consumption;  $I_{CC} = 0.9 \ \mu A$  (maximum)
- Latch-up performance exceeds 100 mA per JESD 78 Class II
- Inputs accept voltages up to 3.6 V
- Low noise overshoot and undershoot < 10 % of V<sub>CC</sub>
- I<sub>OFF</sub> circuitry provides partial power-down mode operation
- Specified from -40 °C to +85 °C and -40 °C to +125 °C

# 3. Ordering information

Type number	Package							
	Temperature range	re range Name Description		Version				
74AUP2G97DP	-40 °C to +125 °C	TSSOP10	plastic thin shrink small outline package; 10 leads; body width 3 mm	SOT552-1				
74AUP2G97GU	-40 °C to +125 °C	XQFN10	plastic, extremely thin quad flat package; no leads; 10 terminals; body 1.40 × 1.80 × 0.50 mm	SOT1160-1				

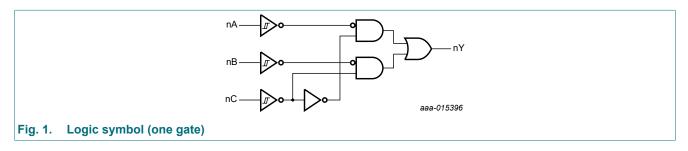
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# 4. Marking

Table 2. Marking				
Type number	Marking code [1]			
74AUP2G97DP	aV			
74AUP2G97GU	aV			

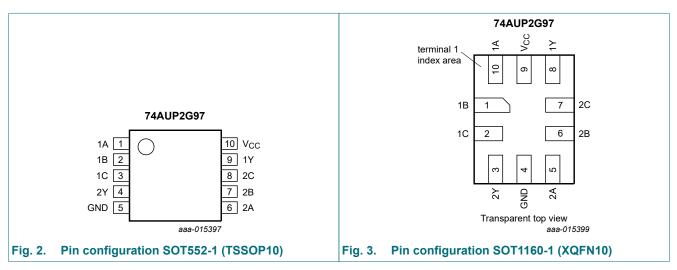
[1] The pin 1 indicator is located on the lower left corner of the device, below the marking code.

# 5. Functional diagram



# 6. Pinning information

### 6.1. Pinning



### 6.2. Pin description

Symbol	Pin	Description	
	SOT552-1	SOT1160-1	
1A, 2A	1, 6	10, 5	data input
1B, 2B	2, 7	1, 6	data input
1C, 2C	3, 8	2, 7	data input
1Y, 2Y	9, 4	8, 3	data output
GND	5	4	ground (0 V)
V <sub>CC</sub>	10	9	supply voltage

# 7. Functional description

#### **Table 4. Function table**

H = HIGH voltage level; L = LOW voltage level.

Input				
nC	nB	nA	nY	
L	L	L	L	
L	L	Н	L	
L	Н	L	Н	
L	Н	Н	Н	
Н	L	L	L	
Н	L	Н	Н	
Н	Н	L	L	
Н	Н	Н	Н	

## 7.1 Logic configurations

7.1. Logic configuration	S
Table 5. Function selection table	
Logic function	Figure
2-input MUX	see Fig. 4
2-input AND	see Fig. 5
2-input OR with one input inverted	see Fig. 6
2-input NAND with one input inverted	see <u>Fig. 6</u>
2-input AND with one input inverted	see Fig. 7
2-input NOR with one input inverted	see Fig. 7
2-input OR	see Fig. 8
Inverter	see <u>Fig. 9</u>
Buffer	see <u>Fig. 10</u>

74AUP2G97

#### Low-power dual PCB configurable multiple function gate

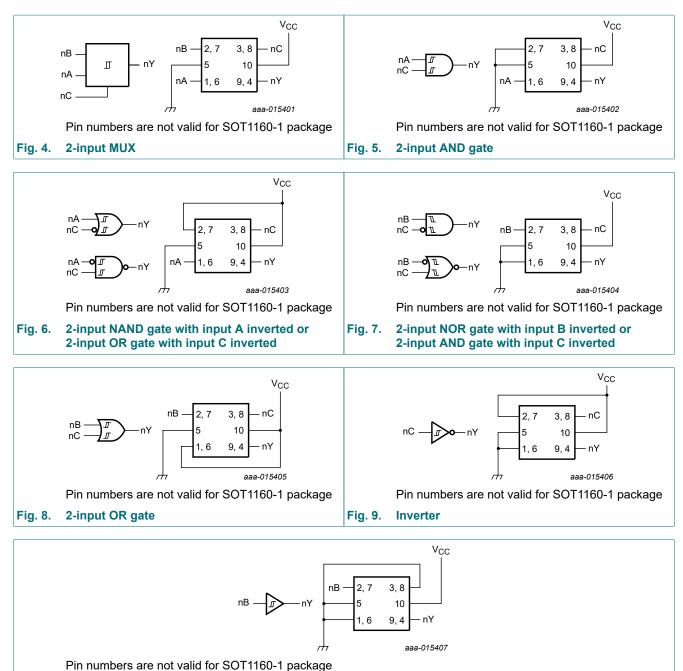


Fig. 10. Buffer

# 8. Limiting values

#### Table 6. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Мах	Unit
V <sub>CC</sub>	supply voltage		-0.5	+4.6	V
I <sub>IK</sub>	input clamping current	V <sub>I</sub> < 0 V	-50	-	mA
VI	input voltage	[1]	-0.5	+4.6	V
I <sub>OK</sub>	output clamping current	V <sub>O</sub> < 0 V	-50	-	mA
Vo	output voltage	Active mode and Power-down mode [1]	-0.5	+4.6	V
lo	output current	$V_{O} = 0 V \text{ to } V_{CC}$	-	±20	mA
I <sub>CC</sub>	supply current		-	50	mA
I <sub>GND</sub>	ground current		-50	-	mA
T <sub>stg</sub>	storage temperature		-65	+150	°C
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> = -40 °C to +125 °C [2]	-	250	mW

[1] The minimum input and output voltage ratings may be exceeded if the input and output current ratings are observed.

[2] For SOT552-1 (TSSOP10) packages: Ptot derates linearly with 8.3 mW/K above 120 °C.

For SOT1160-1 (XQFN10) packages: P<sub>tot</sub> derates linearly with 7.1 mW/K above 115 °C.

# 9. Recommended operating conditions

Table 7. Recommended operating conditions						
-			-			

Symbol	Parameter	Conditions	Min	Мах	Unit
V <sub>CC</sub>	supply voltage		0.8	3.6	V
VI	input voltage		0	3.6	V
Vo	output voltage	Active mode	0	V <sub>CC</sub>	V
		Power-down mode; V <sub>CC</sub> = 0 V	0	3.6	V
T <sub>amb</sub>	ambient temperature		-40	+125	°C

# **10. Static characteristics**

#### Table 8. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Тур	Max	Unit			
T <sub>amb</sub> = 2	T <sub>amb</sub> = 25 °C								
V <sub>OH</sub>	HIGH-level output voltage	$V_{I} = V_{T+} \text{ or } V_{T-}$							
		$I_{O}$ = -20 µA; $V_{CC}$ = 0.8 V to 3.6 V	V <sub>CC</sub> - 0.1	-	-	V			
		I <sub>O</sub> = -1.1 mA; V <sub>CC</sub> = 1.1 V	$0.75 \times V_{CC}$	-	-	V			
		I <sub>O</sub> = -1.7 mA; V <sub>CC</sub> = 1.4 V	1.11	-	-	V			
		I <sub>O</sub> = -1.9 mA; V <sub>CC</sub> = 1.65 V	1.32	-	-	V			
		I <sub>O</sub> = -2.3 mA; V <sub>CC</sub> = 2.3 V	2.05	-	-	V			
		I <sub>O</sub> = -3.1 mA; V <sub>CC</sub> = 2.3 V	1.9	-	-	V			
		I <sub>O</sub> = -2.7 mA; V <sub>CC</sub> = 3.0 V	2.72	-	-	V			
		I <sub>O</sub> = -4.0 mA; V <sub>CC</sub> = 3.0 V	2.6	-	-	V			

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V <sub>OL</sub>	LOW-level output voltage	$V_{I} = V_{T+} \text{ or } V_{T-}$				
		$I_{O}$ = 20 µA; $V_{CC}$ = 0.8 V to 3.6 V	-	-	0.1	V
		I <sub>O</sub> = 1.1 mA; V <sub>CC</sub> = 1.1 V	-	-	0.3 × V <sub>CC</sub>	V
		I <sub>O</sub> = 1.7 mA; V <sub>CC</sub> = 1.4 V	-	-	0.31	V
		I <sub>O</sub> = 1.9 mA; V <sub>CC</sub> = 1.65 V	-	-	0.31	V
		I <sub>O</sub> = 2.3 mA; V <sub>CC</sub> = 2.3 V	-	-	0.31	V
		I <sub>O</sub> = 3.1 mA; V <sub>CC</sub> = 2.3 V	-	-	0.44	V
		I <sub>O</sub> = 2.7 mA; V <sub>CC</sub> = 3.0 V	-	-	0.31	V
		I <sub>O</sub> = 4.0 mA; V <sub>CC</sub> = 3.0 V	-	-	0.44	V
l <sub>l</sub>	input leakage current	V <sub>1</sub> = GND to 3.6 V; V <sub>CC</sub> = 0 V to 3.6 V	-	-	±0.1	μA
I <sub>OFF</sub>	power-off leakage current	$V_1 \text{ or } V_0 = 0 \text{ V to } 3.6 \text{ V; } V_{CC} = 0 \text{ V}$	-	-	±0.2	μA
ΔI <sub>OFF</sub>	additional power-off leakage current	$V_{I} \text{ or } V_{O} = 0 \text{ V to } 3.6 \text{ V}; V_{CC} = 0 \text{ V to } 0.2 \text{ V}$	-	-	±0.2	μA
I <sub>CC</sub>	supply current	$\label{eq:VI} \begin{array}{l} V_{I} = GND \text{ or } V_{CC}; \ I_{O} = 0 \ A; \\ V_{CC} = 0.8 \ V \ to \ 3.6 \ V \end{array}$	-	-	0.5	μA
ΔI <sub>CC</sub>	additional supply current	$V_{I} = V_{CC} - 0.6 \text{ V}; I_{O} = 0 \text{ A}; V_{CC} = 3.3 \text{ V}$ [1]	-	-	40	μA
CI	input capacitance	$V_{CC}$ = 0 V to 3.6 V; $V_I$ = GND or $V_{CC}$	-	1.1	-	pF
Co	output capacitance	$V_{O} = GND; V_{CC} = 0 V$	-	1.7	-	pF
T <sub>amb</sub> = -4	40 °C to +85 °C					
V <sub>OH</sub>	HIGH-level output voltage	$V_{I} = V_{T+} \text{ or } V_{T-}$				
		$I_{O}$ = -20 µA; $V_{CC}$ = 0.8 V to 3.6 V	V <sub>CC</sub> - 0.1	-	-	V
		I <sub>O</sub> = -1.1 mA; V <sub>CC</sub> = 1.1 V	$0.7 \times V_{CC}$	-	-	V
		I <sub>O</sub> = -1.7 mA; V <sub>CC</sub> = 1.4 V	1.03	-	-	V
		I <sub>O</sub> = -1.9 mA; V <sub>CC</sub> = 1.65 V	1.30	-	-	V
		I <sub>O</sub> = -2.3 mA; V <sub>CC</sub> = 2.3 V	1.97	-	-	V
		I <sub>O</sub> = -3.1 mA; V <sub>CC</sub> = 2.3 V	1.85	-	-	V
		I <sub>O</sub> = -2.7 mA; V <sub>CC</sub> = 3.0 V	2.67	-	-	V
		I <sub>O</sub> = -4.0 mA; V <sub>CC</sub> = 3.0 V	2.55	-	-	V
V <sub>OL</sub>	LOW-level output voltage	$V_{I} = V_{T+} \text{ or } V_{T-}$				
		$I_{O}$ = 20 µA; $V_{CC}$ = 0.8 V to 3.6 V	-	-	0.1	V
		I <sub>O</sub> = 1.1 mA; V <sub>CC</sub> = 1.1 V	-	-	$0.3 \times V_{CC}$	V
		I <sub>O</sub> = 1.7 mA; V <sub>CC</sub> = 1.4 V	-	-	0.37	V
		I <sub>O</sub> = 1.9 mA; V <sub>CC</sub> = 1.65 V	-	-	0.35	V
		I <sub>O</sub> = 2.3 mA; V <sub>CC</sub> = 2.3 V	-	-	0.33	V
		I <sub>O</sub> = 3.1 mA; V <sub>CC</sub> = 2.3 V	-	-	0.45	V
		I <sub>O</sub> = 2.7 mA; V <sub>CC</sub> = 3.0 V	-	-	0.33	V
		I <sub>O</sub> = 4.0 mA; V <sub>CC</sub> = 3.0 V	-	-	0.45	V
l <sub>l</sub>	input leakage current	$V_{I}$ = GND to 3.6 V; $V_{CC}$ = 0 V to 3.6 V	-	-	±0.5	μA
I <sub>OFF</sub>	power-off leakage current	$V_{I}$ or $V_{O}$ = 0 V to 3.6 V; $V_{CC}$ = 0 V	-	-	±0.5	μA
ΔI <sub>OFF</sub>	additional power-off leakage current	$V_{I}$ or $V_{O}$ = 0 V to 3.6 V; $V_{CC}$ = 0 V to 0.2 V	-	-	±0.6	μA
I <sub>CC</sub>	supply current		-	-	0.9	μA
ΔI <sub>CC</sub>	additional supply current	$V_1 = V_{CC} - 0.6 \text{ V}; I_0 = 0 \text{ A}; V_{CC} = 3.3 \text{ V}$ [1]	-	-	50	μA

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Symbol	Parameter	Conditions	Min	Тур	Max	Unit
T <sub>amb</sub> = -	40 °C to +125 °C				-	
V <sub>OH</sub>	HIGH-level output voltage	$V_I = V_{T+}$ or $V_{T-}$				
		$I_{O}$ = -20 µA; $V_{CC}$ = 0.8 V to 3.6 V	V <sub>CC</sub> - 0.11	-	-	V
		I <sub>O</sub> = -1.1 mA; V <sub>CC</sub> = 1.1 V	0.6 × V <sub>CC</sub>	-	-	V
		I <sub>O</sub> = -1.7 mA; V <sub>CC</sub> = 1.4 V	0.93	-	-	V
		I <sub>O</sub> = -1.9 mA; V <sub>CC</sub> = 1.65 V	1.17	-	-	V
		I <sub>O</sub> = -2.3 mA; V <sub>CC</sub> = 2.3 V	1.77	-	-	V
		I <sub>O</sub> = -3.1 mA; V <sub>CC</sub> = 2.3 V	1.67	-	-	V
		I <sub>O</sub> = -2.7 mA; V <sub>CC</sub> = 3.0 V	2.40	-	-	V
		I <sub>O</sub> = -4.0 mA; V <sub>CC</sub> = 3.0 V	2.30	-	-	V
V <sub>OL</sub>	LOW-level output voltage	$V_{I} = V_{T+} \text{ or } V_{T-}$				
		$I_{O}$ = 20 µA; $V_{CC}$ = 0.8 V to 3.6 V	-	-	0.11	V
		I <sub>O</sub> = 1.1 mA; V <sub>CC</sub> = 1.1 V	-	-	0.33 × V <sub>CC</sub>	V
		I <sub>O</sub> = 1.7 mA; V <sub>CC</sub> = 1.4 V	-	-	0.41	V
		I <sub>O</sub> = 1.9 mA; V <sub>CC</sub> = 1.65 V	-	-	0.39	V
		I <sub>O</sub> = 2.3 mA; V <sub>CC</sub> = 2.3 V	-	-	0.36	V
		I <sub>O</sub> = 3.1 mA; V <sub>CC</sub> = 2.3 V	-	-	0.50	V
		I <sub>O</sub> = 2.7 mA; V <sub>CC</sub> = 3.0 V	-	-	0.36	V
		I <sub>O</sub> = 4.0 mA; V <sub>CC</sub> = 3.0 V	-	-	0.50	V
lı	input leakage current	$V_{I}$ = GND to 3.6 V; $V_{CC}$ = 0 V to 3.6 V	-	-	±0.75	μA
I <sub>OFF</sub>	power-off leakage current	$V_1$ or $V_0$ = 0 V to 3.6 V; $V_{CC}$ = 0 V	-	-	±0.75	μA
Δl <sub>OFF</sub>	additional power-off leakage current	$V_1$ or $V_0$ = 0 V to 3.6 V; $V_{CC}$ = 0 V to 0.2 V	-	-	±0.75	μA
I <sub>CC</sub>	supply current	$V_{I} = GND \text{ or } V_{CC}; I_{O} = 0 \text{ A};$ $V_{CC} = 0.8 \text{ V to } 3.6 \text{ V}$	-	-	1.4	μA
ΔI <sub>CC</sub>	additional supply current	$V_{I} = V_{CC} - 0.6 V; I_{O} = 0 A; V_{CC} = 3.3 V$ [1]	-	-	75	μA

[1] One input at V\_{CC} - 0.6 V, other input at V\_{CC} or GND.

#### **10.1. Transfer characteristics**

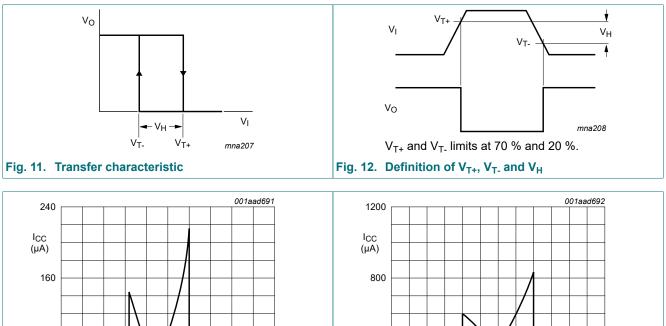
#### Table 9. Transfer characteristics

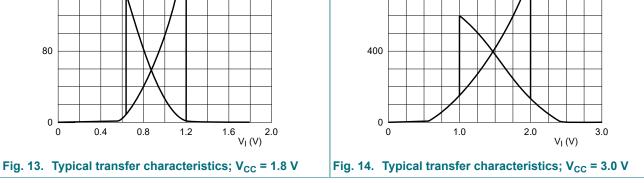
Voltages are referenced to GND (ground = 0 V); for test circuit, see Fig. 16.

Symbol	Parameter	eter Conditions 25 °C			-40 °C to +85 °C		-40 °C to +125 °C		Unit	
			Min	Тур	Max	Min	Max	Min	Max	
V <sub>T+</sub>	positive-going	see Fig. 11 and Fig. 12								
	threshold voltage	V <sub>CC</sub> = 0.8 V	0.30	-	0.60	0.30	0.60	0.30	0.62	V
		V <sub>CC</sub> = 1.1 V	0.53	-	0.90	0.53	0.90	0.53	0.92	V
		V <sub>CC</sub> = 1.4 V	0.74	-	1.11	0.74	1.11	0.74	1.13	V
		V <sub>CC</sub> = 1.65 V	0.91	-	1.29	0.91	1.29	0.91	1.31	V
		V <sub>CC</sub> = 2.3 V	1.37	-	1.77	1.37	1.77	1.37	1.80	V
		V <sub>CC</sub> = 3.0 V	1.88	-	2.29	1.88	2.29	1.88	2.32	V

Symbol	Parameter	Conditions		25 °C		-40 °C to +85 °C		-40 °C to +125 °C		Unit
			Min	Тур	Max	Min	Max	Min	Мах	
V <sub>T-</sub>	negative-going	see Fig. 11 and Fig. 12								
	threshold voltage	V <sub>CC</sub> = 0.8 V	0.10	-	0.60	0.10	0.60	0.10	0.60	V
		V <sub>CC</sub> = 1.1 V	0.26	-	0.65	0.26	0.65	0.26	0.65	V
		V <sub>CC</sub> = 1.4 V	0.39	-	0.75	0.39	0.75	0.39	0.75	V
		V <sub>CC</sub> = 1.65 V	0.47	-	0.84	0.47	0.84	0.47	0.84	V
		V <sub>CC</sub> = 2.3 V	0.69	-	1.04	0.69	1.04	0.69	1.04	V
		V <sub>CC</sub> = 3.0 V	0.88	-	1.24	0.88	1.24	0.88	1.24	V
V <sub>H</sub>	hysteresis voltage	(V <sub>T+</sub> - V <sub>T</sub> .); see <u>Fig. 11</u> , <u>Fig. 12</u> , <u>Fig. 13</u> and <u>Fig. 14</u>								
		V <sub>CC</sub> = 0.8 V	0.07	-	0.50	0.07	0.50	0.07	0.50	V
		V <sub>CC</sub> = 1.1 V	0.08	-	0.46	0.08	0.46	0.08	0.46	V
		V <sub>CC</sub> = 1.4 V	0.18	-	0.56	0.18	0.56	0.18	0.56	V
		V <sub>CC</sub> = 1.65 V	0.27	-	0.66	0.27	0.66	0.27	0.66	V
		V <sub>CC</sub> = 2.3 V	0.53	-	0.92	0.53	0.92	0.53	0.92	V
		V <sub>CC</sub> = 3.0 V	0.79	-	1.31	0.79	1.31	0.79	1.31	V

#### 10.2. Waveforms transfer characteristics





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# **11. Dynamic characteristics**

#### Table 10. Dynamic characteristics

Voltages are referenced to GND (ground = 0 V); for test circuit, see Fig. 16.

Symbol	Parameter	Conditions		25 °C		-40 °C to +85 °C		-40 °C to +125 °C		Unit
			Min	Typ [1]	Мах	Min	Max	Min	Max	
C <sub>L</sub> = 5 p	F	· · · · · · · · · · · · · · · · · · ·								
t <sub>pd</sub>	propagation	nA, nB, nC to nY; see <u>Fig. 15</u> [2]								
	delay	V <sub>CC</sub> = 0.8 V	-	23.0	-	-	-	-	-	ns
		V <sub>CC</sub> = 1.1 V to 1.3 V	2.8	6.6	12.6	2.5	13.0	2.5	13.2	ns
		V <sub>CC</sub> = 1.4 V to 1.6 V	2.3	4.7	7.6	2.5	8.2	2.5	8.6	ns
		V <sub>CC</sub> = 1.65 V to 1.95 V	2.2	3.9	6.2	2.0	6.8	2.0	7.2	ns
		V <sub>CC</sub> = 2.3 V to 2.7 V	2.0	3.2	4.5	1.7	5.1	1.7	5.3	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V	1.9	2.8	3.9	1.5	4.1	1.5	4.3	ns
C <sub>L</sub> = 10	pF	· · · · · · · · · · · · · · · · · · ·				I	1		1	
t <sub>pd</sub>	propagation	nA, nB, nC to nY; see <u>Fig. 15</u> [2]								
	delay	V <sub>CC</sub> = 0.8 V	-	26.6	-	-	-	-	-	ns
		V <sub>CC</sub> = 1.1 V to 1.3 V	3.2	7.4	14.3	2.9	14.9	2.9	15.2	ns
		V <sub>CC</sub> = 1.4 V to 1.6 V	2.6	5.3	8.7	2.8	9.4	2.8	9.8	ns
		V <sub>CC</sub> = 1.65 V to 1.95 V	2.5	4.5	7.0	2.3	7.8	2.3	8.2	ns
		V <sub>CC</sub> = 2.3 V to 2.7 V	2.4	3.7	5.2	2.1	5.9	2.1	6.1	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V	2.3	3.4	4.6	1.9	4.9	1.9	5.1	ns
C <sub>L</sub> = 15	pF	· · · · · ·				1				-
t <sub>pd</sub>	propagation	nA, nB, nC to nY; see Fig. 15 [2]								
	delay	V <sub>CC</sub> = 0.8 V	-	30.1	-	-	-	-	-	ns
		V <sub>CC</sub> = 1.1 V to 1.3 V	3.6	8.2	16.0	3.2	16.7	3.2	17.0	ns
		V <sub>CC</sub> = 1.4 V to 1.6 V	2.9	5.9	9.6	3.1	10.4	3.1	10.9	ns
		V <sub>CC</sub> = 1.65 V to 1.95 V	2.8	5.0	7.8	2.5	8.7	2.5	9.1	ns
		V <sub>CC</sub> = 2.3 V to 2.7 V	2.7	4.2	5.8	2.4	6.5	2.4	6.9	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V	2.5	3.8	5.1	2.2	5.5	2.2	5.7	ns
C <sub>L</sub> = 30	pF	· · · · · · · · · · · · · · · · · · ·		· · · · · ·		1				1
t <sub>pd</sub>	propagation	nA, nB, nC to nY; see <u>Fig. 15</u> [2]								
	delay	V <sub>CC</sub> = 0.8 V	-	38.3	-	-	-	-	-	ns
		V <sub>CC</sub> = 1.1 V to 1.3 V	4.6	10.5	20.9	4.0	21.8	4.0	22.2	ns
		V <sub>CC</sub> = 1.4 V to 1.6 V	3.7	7.4	12.2	3.8	13.3	3.8	14.0	ns
		V <sub>CC</sub> = 1.65 V to 1.95 V	3.5	6.3	9.9	3.2	11.1	3.2	11.8	ns
		$V_{CC}$ = 2.3 V to 2.7 V	3.4	5.3	7.4	3.1	8.3	3.1	8.8	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V	3.2	4.9	6.6	2.8	7.0	2.8	7.4	ns

#### Low-power dual PCB configurable multiple function gate

Symbol	Parameter	Conditions		25 °C		-40 °C to +85 °C		-40 °C to +125 °C		Unit
			Min	Typ [1]	Мах	Min	Max	Min	Max	
C <sub>L</sub> = 5 p	F, 10 pF, 15 pl	F and 30 pF								
C <sub>PD</sub>	power dissipation capacitance	$f_i = 1 \text{ MHz}; V_1 = \text{GND to } V_{\text{CC}}$	3]							
		V <sub>CC</sub> = 0.8 V	-	2.6	-	-	-	-	-	pF
		V <sub>CC</sub> = 1.1 V to 1.3 V	-	2.8	-	-	-	-	-	pF
		V <sub>CC</sub> = 1.4 V to 1.6 V	-	2.9	-	-	-	-	-	pF
		V <sub>CC</sub> = 1.65 V to 1.95 V	-	3.1	-	-	-	-	-	pF
		V <sub>CC</sub> = 2.3 V to 2.7 V	-	3.7	-	-	-	-	-	pF
		V <sub>CC</sub> = 3.0 V to 3.6 V	-	4.3	-	-	-	-	-	pF

All typical values are measured at nominal V<sub>CC</sub>. [1]

[1] Fin typical values are included to include to the formula  $V_{CC}$ . [2]  $t_{pd}$  is the same as  $t_{PLH}$  and  $t_{PHL}$ [3]  $C_{PD}$  is used to determine the dynamic power dissipation ( $P_D$  in  $\mu$ W).  $P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \Sigma (C_L \times V_{CC}^2 \times f_o)$  where:

 $f_i$  = input frequency in MHz;

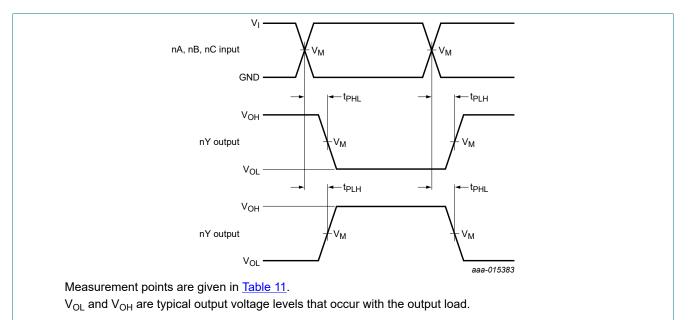
 $f_o$  = output frequency in MHz;

C<sub>L</sub> = output load capacitance in pF;

V<sub>CC</sub> = supply voltage in V;

N = number of inputs switching;

 $\Sigma(C_L \times V_{CC}^2 \times f_o)$  = sum of the outputs.

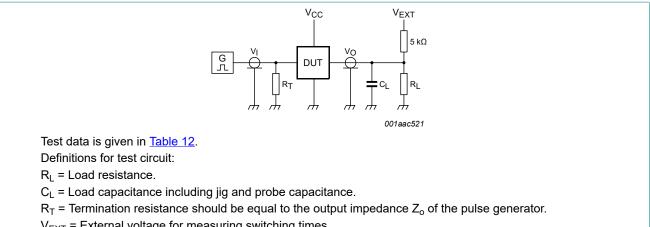


#### 11.1. Waveforms and test circuit

Fig. 15. Input nA, nB and nC to output nY propagation delay times

#### Table 11. Measurement points

Supply voltage	Output	Input		
V <sub>cc</sub>	V <sub>M</sub>	V <sub>M</sub>	VI	t <sub>r</sub> = t <sub>f</sub>
0.8 V to 3.6 V	$0.5 \times V_{CC}$	$0.5 \times V_{CC}$	V <sub>CC</sub>	≤ 3.0 ns



V<sub>EXT</sub> = External voltage for measuring switching times.

#### Fig. 16. Test circuit for measuring switching times

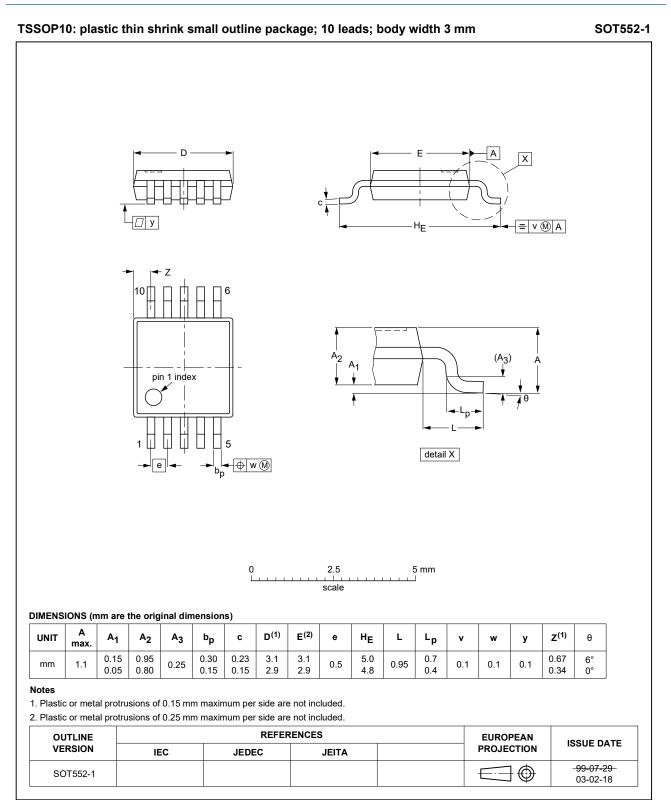
#### Table 12. Test data

Supply voltage	Load	V <sub>EXT</sub>			
V <sub>cc</sub>	CL	R <sub>L</sub> [1]	t <sub>PLH</sub> , t <sub>PHL</sub>	t <sub>PZH</sub> , t <sub>PHZ</sub>	t <sub>PZL</sub> , t <sub>PLZ</sub>
0.8 V to 3.6 V	5 pF, 10 pF, 15 pF and 30 pF	5 kΩ or 1 MΩ	open	GND	2V <sub>CC</sub>

For measuring enable and disable times,  $R_L = 5 k\Omega$ . [1]

For measuring propagation delays, setup and hold times and pulse width R<sub>L</sub> = 1 M $\Omega$ .

# 12. Package outline



#### Fig. 17. Package outline SOT552-1 (TSSOP10)

<sup>74</sup>AUP2G97

#### Low-power dual PCB configurable multiple function gate

#### XQFN10: plastic, extremely thin quad flat package; no leads; 10 terminals; body 1.40 x 1.80 x 0.50 mm

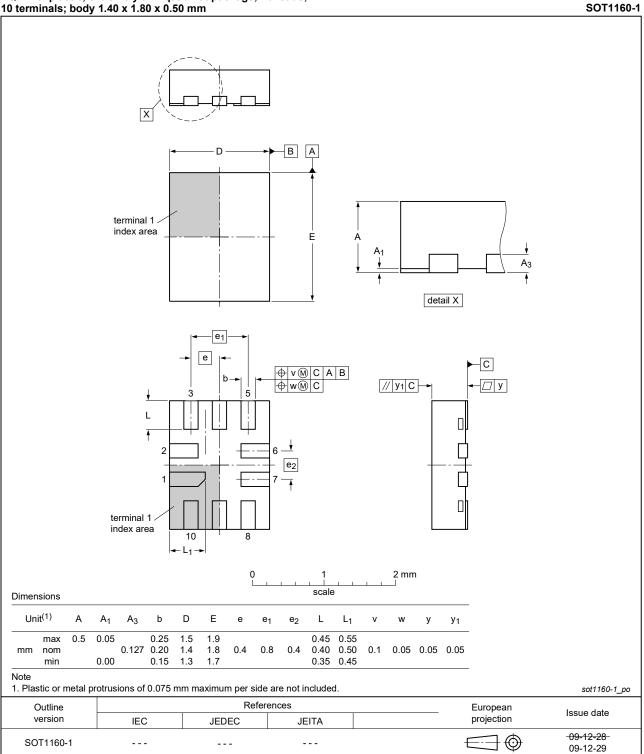


Fig. 18. Package outline SOT1160-1 (XQFN10)

# 13. Abbreviations

Table 13. Abbreviati	ons
Acronym	Description
CDM	Charged Device Model
DUT	Device Under Test
ESD	ElectroStatic Discharge
HBM	Human Body Model
MM	Machine Model
РСВ	Printed-Circuit Board

# 14. Revision history

#### Table 14. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
74AUP2G97 v.3	20190722	Product data sheet	-	74AUP2G97 v.2
Modifications:	Nexperia. <ul> <li>Legal texts have</li> </ul>	this data sheet has been redesi ave been adapted to the new cor 74AUP2G97GF (SOT1081-2) re	npany name where	
74AUP2G97 v.2	20151202	Product data sheet	-	74AUP2G97 v.1
Modifications:		ue temperature range TSSOP10 AUP2G97GM (SOT1049-3).	(74AUP2G97DP)	changed from 85 °C to 125 °C.
74AUP2G97 v.1	20141104	Product data sheet	-	-

# 15. Legal information

#### Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

 Please consult the most recently issued document before initiating or completing a design.

- [2] The term 'short data sheet' is explained in section "Definitions".
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